## NSN 5961-01-294-5798

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-294-5798 **Inclosure Material:** Plastic **Overall Length:** Between 0.180 inches and 0.200 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** 0.185 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -30.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source and -30.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 360.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No